

Physics II (PH 102)

Electromagnetism (Lecture 11)

Udit Raha

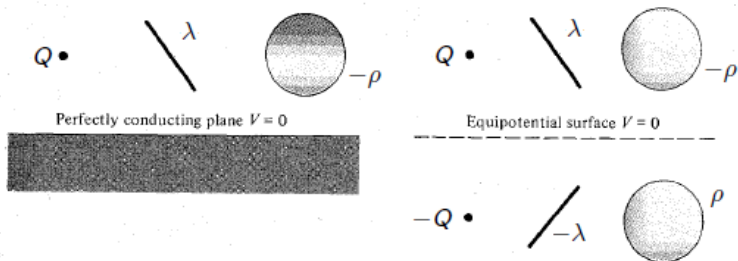
Indian Institute of Technology Guwahati

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Method of Images: Avoids solving PDEs in Boundary Valued Problems

Method of Images: Invented by Lord Kelvin in 1848, commonly used to determine V , \mathbf{E} and σ (surface charge density) due to static charge configurations in the presence of a system of conductors.

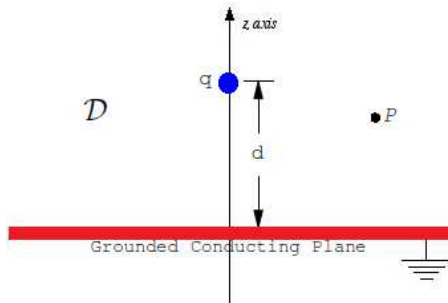
1. **Central idea:** Map the original hard problem to another easier problem, *but satisfying the same boundary conditions*. Then *Uniqueness Theorem* guarantees the correctness of the solution.
2. **Use Fact:** All conducting surfaces are represented by equipotentials.
3. **Strategy:** All **Real charge** configurations and conducting surfaces are replaced by the same Real charges, equipotential surfaces and some additional **fictitious** charges or charge distributions in the conducting region, called **Image Charges**.



The Classic Image Problem

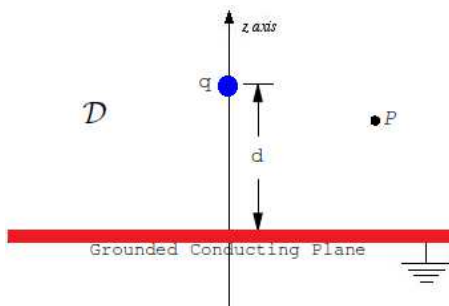
Example

Suppose a point charge q is held at a distance d above a infinite grounded conducting plane. What is the Electrostatic Potential at point P in the non-conducting region \mathcal{D} above the conducting plane?



- ▶ The Electrostatic Potential V at point $P \equiv (x, y, z)$ will be due to point charge q and the **induced surface charges**.
- ▶ **Problem is, we do not know $\sigma(x, y)$ a priori !** How to determine $V(x, y, z)$ without directly knowing $\sigma(x, y)$ on the conducting plane?

Infinite grounded conducting plane



Set up a co-ordinate system with xy -plane as the given infinite conducting plane and q lies on the z -axis:

- ▶ Sol. Domain: $\mathcal{D} = \{\mathbf{r} \mid z > 0\}$
- ▶ Boundary Surfaces of \mathcal{D} :

$$S = \{xy\text{-plane}\} \cup S_{\infty+}$$

- ▶ Point Charge density:
 $\rho(\mathbf{r}) = q\delta^3(\mathbf{r} - \mathbf{r}_0)$; $\mathbf{r}_0 = (0, 0, d)$

- ▶ $V(x, y, z)$ satisfies **Poisson's Equation** $\forall \mathbf{r} \in \mathcal{D}$:

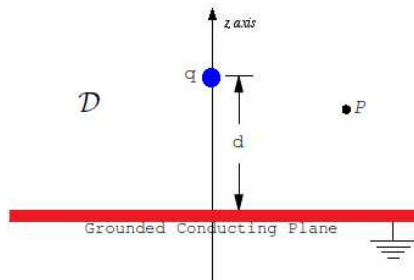
$$\nabla^2 V(\mathbf{r}) = \frac{1}{\epsilon_0} \rho(\mathbf{r})$$

- ▶ **Boundary Condition** on V in the original problem:

$$V(S) = 0, \quad \forall \mathbf{S} \in S.$$

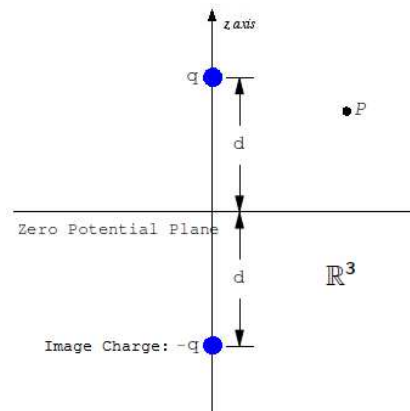
Infinite grounded conducting plane (contd.)

Real System is mapped on to the **Fictitious System** satisfying the same b.c.



Potential $V(x, y, z)$ is ONLY needed in non-conducting region \mathcal{D}

The Real System



Potential $V'(x, y, z)$ defined in the whole of \mathbb{R}^3

The Fictitious System

Infinite grounded conducting plane (contd.)

Consider the **Fictitious System**:

- ▶ Charge distribution: $\rho'(\mathbf{r}) = q\delta^3(\mathbf{r} - \mathbf{r}_0) + (-q)\delta^3(\mathbf{r} + \mathbf{r}_0)$; $\mathbf{r}_0 = (0, 0, d)$
- ▶ Electrostatic Potential in all of $\mathbb{R}^3 \rightarrow$ Trivial to calculate!

$$V'(x, y, z) = \frac{1}{4\pi\epsilon_0} \left[\frac{q}{\sqrt{x^2 + y^2 + (z - d)^2}} + \frac{(-q)}{\sqrt{x^2 + y^2 + (z + d)^2}} \right]$$

- ▶ $V'(\mathbf{r})$ satisfies **Poisson's Equation** $\forall \mathbf{r} \in \mathbb{R}^3$:

$$\nabla^2 V'(\mathbf{r}) = \frac{1}{\epsilon_0} \rho'(\mathbf{r})$$

- ▶ **Boundary Condition**: $V'(\mathbf{S}') = 0$, $\forall \mathbf{S}' \in S' = \{\text{xy-plane}\} \cup S_\infty$

1. Real charge configuration in the common region \mathcal{D} is identical:

$$\rho'(\mathbf{r})|_{\mathcal{D}} \xrightarrow{z>0} \rho(\mathbf{r})$$

2. Boundary conditions in the common region \mathcal{D} are identical:

$$\nabla^2 V' = \frac{1}{\epsilon_0} \rho' \quad \text{over } \mathbb{R}^3 \quad \xrightarrow{z>0} \quad \nabla^2 V = \frac{1}{\epsilon_0} \rho \quad \text{over } \mathcal{D} \subset \mathbb{R}^3,$$

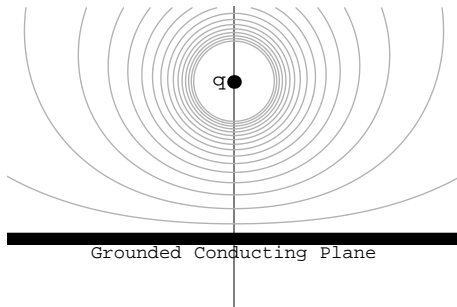
$$V' = 0 \quad \text{on } S' \quad \xrightarrow{z>0} \quad V = 0 \quad \text{on } S \subset S'$$

Infinite grounded conducting plane: Potential

- **Uniqueness Theorem** guarantees unique solution in \mathcal{D} , i.e., $V = V'$
- Thus, we found the solution to the original problem!

Electrostatic Potential in \mathcal{D} : $V(x, y, z) = V'(x, y, z \geq 0)$, i.e.,

$$V(x, y, z) = \frac{q}{4\pi\epsilon_0} \left[\frac{1}{\sqrt{x^2 + y^2 + (z - d)^2}} - \frac{1}{\sqrt{x^2 + y^2 + (z + d)^2}} \right]$$

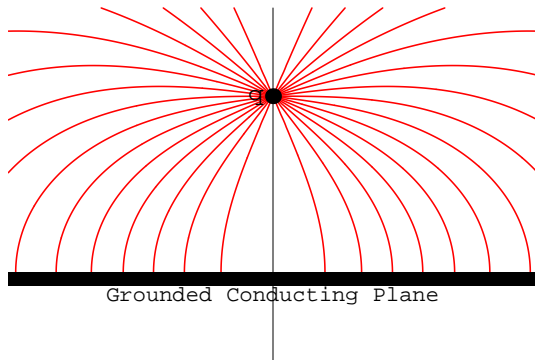


Note: We *needn't* bother that $V = V'$ yields wrong result for $z < 0$!

Infinite grounded conducting plane: Electric Field

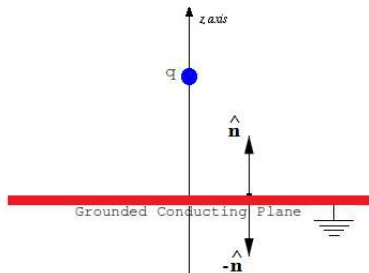
Electrostatic Field in \mathcal{D} : $\mathbf{E}(x, y, z) = \mathbf{E}'(x, y, z \geq 0) = -\nabla V(x, y, z)$, i.e.,

$$\mathbf{E}(x, y, z) = \frac{q}{4\pi\epsilon_0} \left[\frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z-d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z-d)^2)^{3/2}} - \frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z+d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z+d)^2)^{3/2}} \right]$$



Note: Again we *needn't bother* that $\mathbf{E}(\mathbf{r}) = \mathbf{E}'(\mathbf{r})$ yields wrong result for $z < 0$!

Infinite grounded conducting plane: Surface Charge Density



► Normal to conductor: $\pm \hat{n} = \pm \hat{k}$

► Induced surface charge density $E_{\perp} = \sigma/\epsilon_0$:

$$\sigma(x, y) = -\epsilon_0 \left. \frac{\partial V(x, y, z)}{\partial n} \right|_{z=0}$$

$$\equiv \epsilon_0 \mathbf{E}(x, y, z=0) \cdot \hat{k}$$

$$\sigma(x, y) = -\frac{q}{2\pi} \frac{d}{(x^2 + y^2 + d^2)^{3/2}}$$

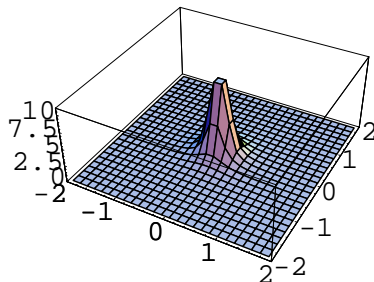
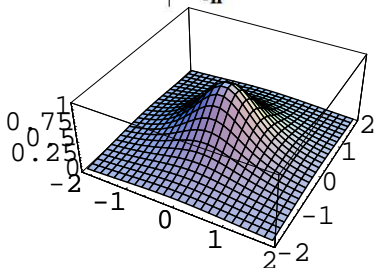


Figure shows $|\sigma|$, for $d=1$ and $d=0.1$

⇒ Maximum induced charge density is right below the point charge

Infinite grounded conducting plane: Total Induced Charge

- Total induced surface charge: (with $dA = dx dy = s ds d\phi$)

$$\begin{aligned} Q_{\text{induced}} &= \iint_{xy\text{-plane}} \sigma(x, y) dA = - \int_{-\infty}^{\infty} dx \int_{-\infty}^{\infty} dy \frac{qd}{2\pi} \frac{1}{(x^2 + y^2 + d^2)^{3/2}} \\ &= -\frac{qd}{2\pi} \int_0^{\infty} \frac{s ds}{(s^2 + d^2)^{3/2}} \int_0^{2\pi} d\phi \\ &= -\frac{qd}{2\pi} \left[-\frac{1}{(s^2 + d^2)^{1/2}} \right]_{s=0}^{s=\infty} (2\pi) \\ Q_{\text{induced}} &= -q \end{aligned}$$

Infinite grounded conducting plane: Force on Real Charge q

Electric Field at $P(x, y, z)$ in \mathcal{D} , that we have already calculated:

$$\mathbf{E}(x, y, z) = \frac{1}{4\pi\epsilon_0} \left[q \left(\frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z-d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z-d)^2)^{3/2}} \right) + (-q) \left(\frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z+d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z+d)^2)^{3/2}} \right) \right]$$

- ▶ The first (second) term is the field due to the *Real Charge* q (*Image Charge* $-q$).
- ▶ Electric Field \rightarrow *Induced charges* \equiv Electric Field \rightarrow *Image charge*:

$$\mathbf{E}_{\text{induced}}(x, y, z) \equiv \mathbf{E}_{\text{image}}(x, y, z) = \frac{(-q)}{4\pi\epsilon_0} \frac{x\hat{\mathbf{i}} + y\hat{\mathbf{j}} + (z+d)\hat{\mathbf{k}}}{(x^2 + y^2 + (z+d)^2)^{3/2}}$$

- ▶ Force on q due to conducting plane \equiv Force on q due to Image charge:

$$\begin{aligned} \mathbf{F}_q &= q\mathbf{E}_{\text{induced}}(0, 0, d) \equiv q\mathbf{E}_{\text{image}}(0, 0, d) \\ &= -\frac{q^2\hat{\mathbf{z}}}{4\pi\epsilon_0(2d)^2} \rightarrow \text{Attractive force} \end{aligned}$$

***QUESTION:** Is there any difference in calculated physical quantities in non-conducting region \mathcal{D} , between those obtained from the *Fictitious System* (charge-image) and those from the *Real System* (charge-conductor)?

Infinite grounded conducting plane: Electrostatic Energy??

- **Configuration energy of *Real System*:**

Work done by external agent to assemble the **charge-conductor system** is

$$W_1^{\text{ext}}(\text{Real}) = - \int_{z=\infty}^{z=d} \mathbf{F}_q(z) \cdot d\mathbf{z} = \int_{\infty}^d \frac{q^2 dz}{4\pi\epsilon_0(2z)^2} = -\frac{1}{2} \left(\frac{q^2}{8\pi\epsilon_0 d} \right)$$

- **Configuration energy of *Fictitious System*:**

Work done by external agent to assemble the **charge-image system** is

$$W_2^{\text{ext}}(\text{Fictitious}) = -\frac{q^2}{4\pi\epsilon_0(2d)} = -\frac{q^2}{8\pi\epsilon_0 d}!$$

⇒ It takes only half the amount of energy to assemble the Real System!!

- Intuitive way of understanding this difference is to use the **integral formula**:

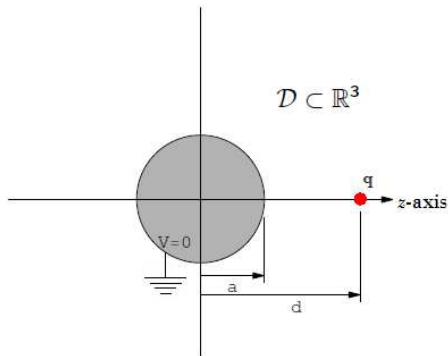
$$U_E(\text{Fictitious}) = \frac{\epsilon_0}{2} \iiint_{\mathbb{R}^3} E^2 dV = 2 \cdot \frac{\epsilon_0}{2} \iiint_{\mathcal{D}} E^2 dV = 2U_E(\text{Real}).$$

⇒ The true domain of integration \mathcal{D} is only half the domain \mathbb{R}^3 for the Fictitious System.

Another classic image problem: Grounded Conducting Sphere

Example

Consider a grounded conducting sphere of radius a and a charge q held at a distance of d from the center. What is the potential in region \mathcal{D} outside the conducting sphere?



Potential $V(x, y, z)$ is needed in \mathcal{D}

The Real System

- ▶ Set up co-ordinate system with z-axis along the line joining the center and q
- ▶ Domain: $\mathcal{D} \subset \mathbb{R}^3 = \{\mathbf{r} \mid r > a\}$
- ▶ Surface/s: $S = \{\mathbf{r} \mid r = a\} \cup S_\infty$
- ▶ Point charge density:

$$\rho(\mathbf{r}) = q\delta^3(\mathbf{r} - d\hat{\mathbf{k}})$$

- ▶ $V(\mathbf{r})$ satisfies **Poisson's Equation**:

$$\nabla^2 V(\mathbf{r}) = \frac{1}{\epsilon_0} \rho(\mathbf{r}), \quad \forall \mathbf{r} \in \mathcal{D}$$

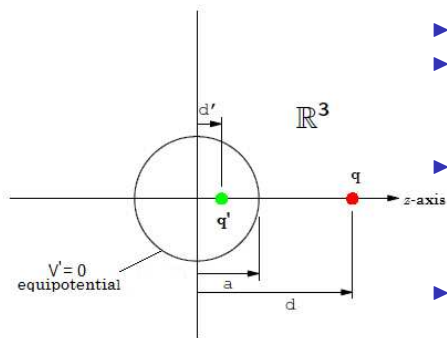
- ▶ **Boundary Condition** for Potential:

$$V(S) = 0, \quad \forall S \in S$$

Grounded Conducting Sphere

Replace Real System with Fictitious System: Real charge q , Image charge q' & Equipotential surface $\Rightarrow V'(\mathbf{r})$ in \mathbb{R}^3 is identical to $V(\mathbf{r})$ in \mathcal{D} .

Note: You should never put the Image charge in \mathcal{D} where you want to calculate the potential. It should not matter if V' yields the wrong answer outside \mathcal{D} !



► Location of q' is $(0, 0, d')$ with $d' < a$

► Point charge densities:

$$\rho'(\mathbf{r}) = \left[q\delta^3(\mathbf{r} - d\hat{\mathbf{k}}) + q'\delta^3(\mathbf{r} - d'\hat{\mathbf{k}}) \right] \Big|_{\mathcal{D}} \xrightarrow{r>a} \rho(\mathbf{r})$$

► V' & V satisfy Poisson's Eqns. in \mathbb{R}^3 & \mathcal{D} :

$$\nabla^2 V' = \frac{\rho'}{\epsilon_0} \xrightarrow{r>a} \nabla^2 V = \frac{\rho}{\epsilon_0}$$

► V' & V satisfy BC in \mathbb{R}^3 & \mathcal{D} :

$$V'(a, \theta, \phi) = V(a, \theta, \phi) = 0$$

$$V'(\mathbf{S}) = V(\mathbf{S}) = 0 \quad .$$

Potential $V'(x, y, z)$ defined in \mathbb{R}^3

The Fictitious System

If such a q' and d' can be found, then we have nailed the problem!